

MGBR30V50C

DUAL MOS GATED BARRIER RECTIFIERS

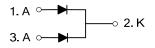
DESCRIPTION

The UTC **MGBR30V50C** is a dual mos gated barrier rectifiers, it uses UTC's advanced technology to provide customers with low forward voltage drop and high switching speed, etc.

FEATURES

* Very low forward voltage drop* High switching speed





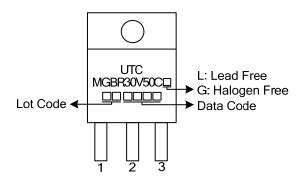
ORDERING INFORMATION

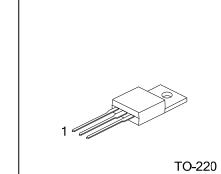
Ordering Number		Deekege	Pin Assignment			Deaking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
MGBR30V50CL-TA3-T	MGBR30V50CG-TA3-T	TO-220	Α	К	Α	Tube	

Note: Pin Assignment: A: Anode, K: Cathode

MGBR30V50CL- <u>TA3-T</u> (1)Packing Type	(1) T: Tube
(2)Package Type	(2) TA3: TO-220
(3)Lead Free	(3) L: Lead Free, G: Halogen Free

MARKING INFORMATION





■ ABSOLUTE MAXIMUM RATINGS (PER LEG) (T_A=25°C unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%.

Ter edpacitance load, derate carrent by 2070.			
PARAMETER	SYMBOL	RATINGS	UNIT
DC Blocking Voltage	V _{RM}	50	V
Working Peak Reverse Voltage	V _{RWM}	50	V
Peak Repetitive Reverse Voltage	V _{RRM}	50	V
Average Destified Output Output Per Leg	l _o	15	А
Average Rectified Output Current Per Device Total		30	А
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	250	А
Operating Junction Temperature	TJ	-65~+150	°C
Storage Temperature	T _{STG}	-65~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL CHARACTERISTICS (PER LEG)

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Case	θ _{JC}	2	°C/W

■ ELECTRICAL CHARACTERISTICS (PER LEG) (T_A =25°C unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	V _{(BR)R}	I _R =0.50mA	50			V
Forward Voltage Drop	Vri	I _F =15A, T _J =25°C			0.55	V
		I _F =15A, T _J =125°C			0.50	V
Leakage Current (Note 1)	RM	V _R =50V, T _J =25°C			500	μA
		V _R =50V, T _J =125°C			100	mA

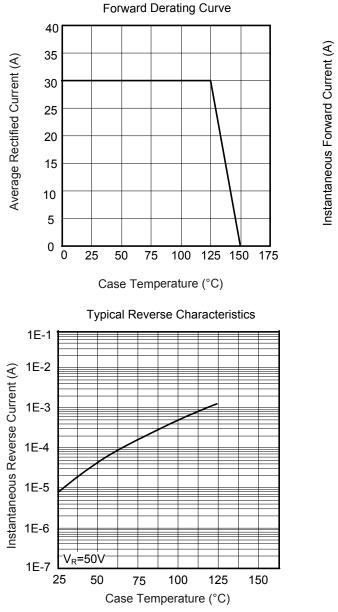
Notes: 1. Short duration pulse test used to minimize self-heating effect.

2. Thermal resistance junction to case mounted on heatsink.



MGBR30V50C

TYPICAL CHARACTERISTICS



Typical Forward Characteristics

Instantaneous Forward Voltage (V)

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